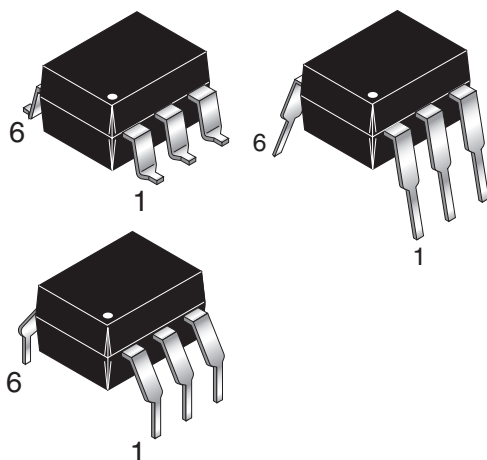


MOC8111

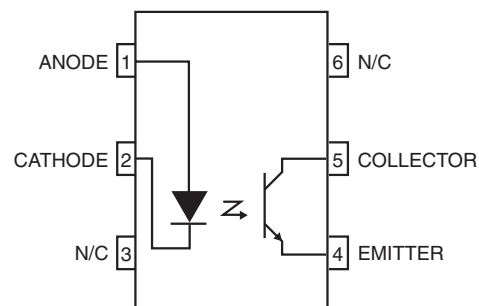
MOC8112

MOC8113

PACKAGE



SCHEMATIC



DESCRIPTION

The MOC811X series consists of a Gallium Arsenide IRED coupled with an NPN phototransistor. The base of the transistor is not bonded to an external pin for improved noise immunity

FEATURES

- High isolation voltage
5300 VAC RMS—1 minute
- High BV_{CEO} minimum 70 Volts
- Current transfer ratio in selected groups:
MOC8111: 20% min.
MOC8112: 50% min.
MOC8113: 100% min.
- Maximum switching time in saturation specified
- Underwriters Laboratory (UL) recognized (File #E90700)
- VDE recognized (File #94766)

APPLICATIONS

- Power Supply Regulators
- Digital Logic Inputs
- Microprocessor Inputs
- Appliance Sensor Systems
- Industrial Controls

6-PIN DIP OPTOCOUPLEDERS FOR POWER SUPPLY APPLICATIONS (NO BASE CONNECTION)

MOC8111

MOC8112

MOC8113

ABSOLUTE MAXIMUM RATINGS (T _A =25°C Unless otherwise specified)			
Parameter	Symbol	Value	Unit
INPUT LED			
Forward Current – Continuous	I _F	90	mA
Forward Current – Peak (PW = 1μs, 300pps)	I _F (pk)	3	A
Reverse Voltage	V _R	6	Volts
LED Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	135	mW
		1.8	mW/°C
OUTPUT TRANSISTOR			
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	200	mW
		2.67	mW/°C
TOTAL DEVICE			
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C	P _D	260	mW
		3.5	mW/°C
Ambient Operating Temperature Range	T _{OPR}	-55 to +100	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Lead Soldering Temperature (1/16” from case, 10 sec. duration)	T _{SOL}	260	°C

MOC8111

MOC8112

MOC8113

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise specified)

INDIVIDUAL COMPONENT CHARACTERISTICS

Parameter	Test Conditions	Symbol	Device	Min	Typ	Max	Unit
EMITTER							
Input Forward Voltage	$I_F = 60\text{ mA}$	V_F	All		1.35	1.65	V
	$I_F = 10\text{ mA}$				1.15	1.50	
Reverse Voltage	$I_R = 10\text{ }\mu\text{A}$	V_R	All	6.0	15		V
Capacitance	$V_F = 0\text{ V}, f = 1.0\text{ MHz}$	C_J	All		50		pF
	$V_F = 1\text{ V}, f = 1.0\text{ MHz}$				65		
Reverse Leakage Current	$V_R = 3.0\text{ V}$	I_R	All		.35	10	μA
DETECTOR							
Breakdown Voltage Collector to Emitter	$I_C = 1.0\text{ mA}, I_F = 0$	BV_{CEO}	All	70			V
Breakdown Voltage Emitter to Collector	$I_E = 100\text{ }\mu\text{A}, I_F = 0$	BV_{ECO}	All	7			V
Leakage Current Collector to Emitter	$V_{CE} = 10\text{ V}, I_F = 0$	I_{CEO}	All		5	50	V
Capacitance Collector to Emitter	$V_{CE} = 0\text{ V}, f = 1\text{ MHz}$	C_{CE}	All		8		pF

ISOLATION CHARACTERISTICS

Characteristic	Test Conditions	Symbol	Min	Typ	Max	Units
Input-Output Isolation Voltage	$f = 60\text{ Hz}, t = 1\text{ min.}$	V_{ISO}	5300			V_{RMS}
Isolation Resistance	$V_{I-O} = 500\text{ VDC}$	R_{ISO}	10^{11}			Ω
Isolation Capacitance	$V_{I-O} = 0, f = 1\text{ MHz}$	C_{ISO}		0.5		pF

6-PIN DIP OPTOCOUPLEDERS FOR POWER SUPPLY APPLICATIONS (NO BASE CONNECTION)

MOC8111

MOC8112

MOC8113

TRANSFER CHARACTERISTICS (T _A = 25°C Unless otherwise specified)							
DC CHARACTERISTICS	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Output/Input Current Transfer Ratio	I _F = 10 mA, V _{CE} = 5V	CTR	MOC8111	20			%
			MOC8112	50			
			MOC8113	100			
Collector-Emitter Saturation Voltage	I _F = 10 mA, I _C = 2.5 mA	V _{CE(SAT)}	All		0.27	0.4	V
AC CHARACTERISTICS	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Non-Saturated Switching Times	R _L = 100 Ω, I _C = 2 mA, V _{CC} = 10 V See Figure 7						
Turn-On Time		t _{on}	All		6.0	10	μS
Turn-Off Time		t _{off}	All		5.5	10	μS
Saturated Switching Times							
Turn-On Time	I _F = 20 mA, V _{CE} = 0.4 V	t _{on}	MOC8111		3.0	5.5	μS
	I _F = 10 mA, V _{CE} = 0.4 V		MOC812, MOC8113		4.2	8.0	
Rise-Time	I _F = 20 mA, V _{CE} = 0.4 V	t _r	MOC8111		2.0	4.0	μS
	I _F = 10 mA, V _{CE} = 0.4 V		MOC812, MOC8113		3.0	6.0	
Turn-Off Time	I _F = 20 mA, V _{CE} = 0.4 V	t _{off}	MOC8111		18	34	μS
	I _F = 10 mA, V _{CE} = 0.4 V		MOC812, MOC8113		23	39	
Fall-Time	I _F = 20 mA, V _{CE} = 0.4 V	t _f	MOC8111		11	20	μS
	I _F = 10 mA, V _{CE} = 0.4 V		MOC812, MOC8113		14	24	

MOC8111

MOC8112

MOC8113

TYPICAL PERFORMANCE CURVES

Fig. 1 LED Forward Voltage vs. Forward Current

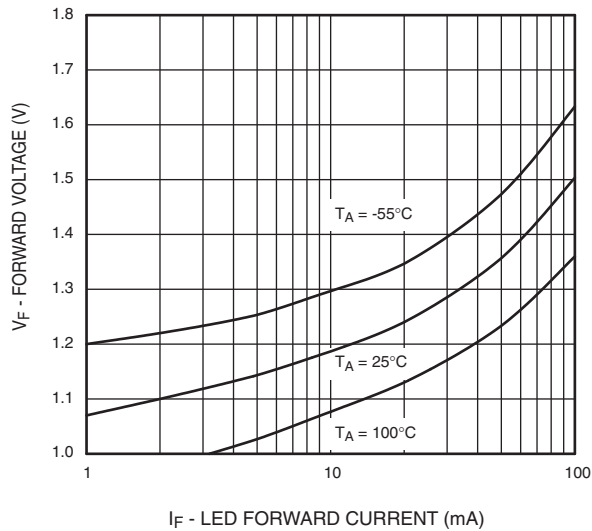


Fig. 2 Normalized CTR vs. Forward Current

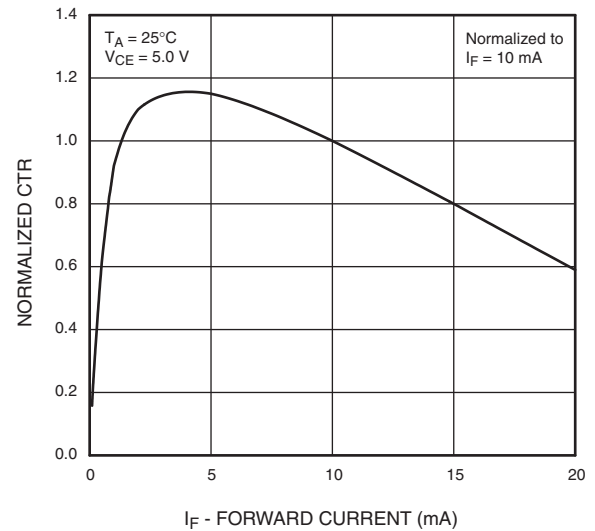


Fig. 3 Normalized CTR vs. Ambient Temperature

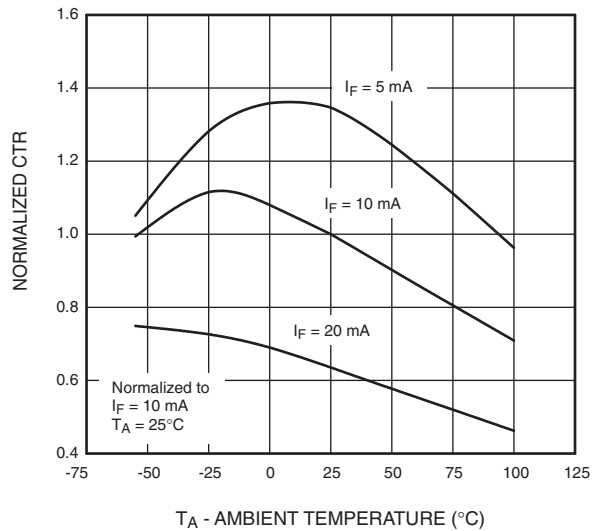
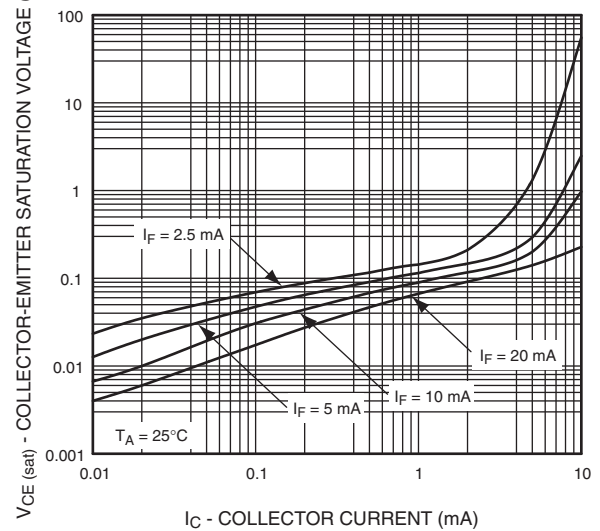


Fig. 4 Collector Emitter Saturation Voltage vs Collector Current



MOC8111

MOC8112

MOC8113

TYPICAL PERFORMANCE CURVES (continued)

Fig. 5 Switching Speed vs. Load Resistor

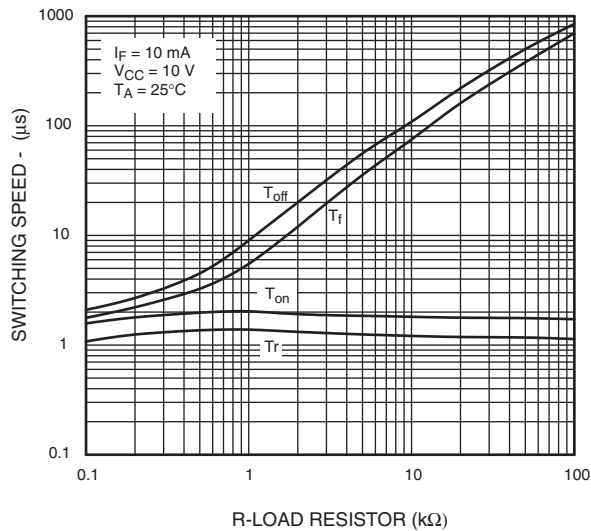


Fig. 6 Dark current vs. Ambient Temperature.

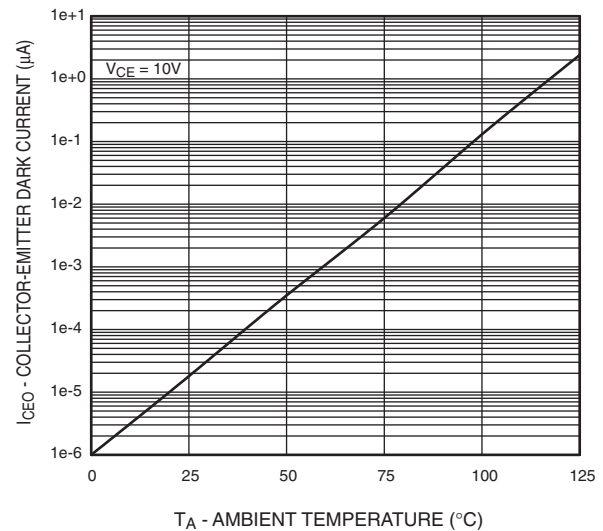
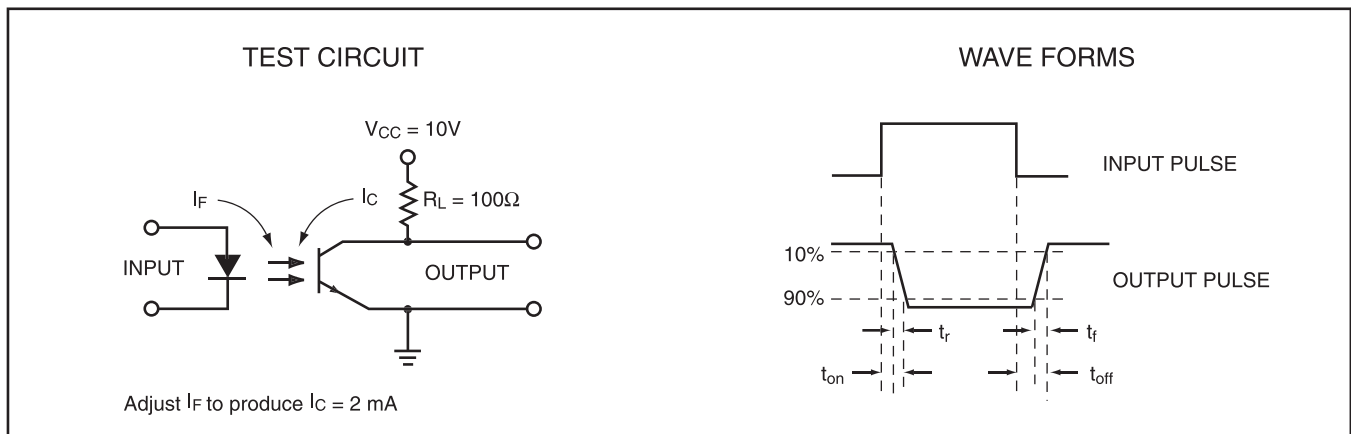


Figure 7. Switching Time Test Circuit and Waveforms

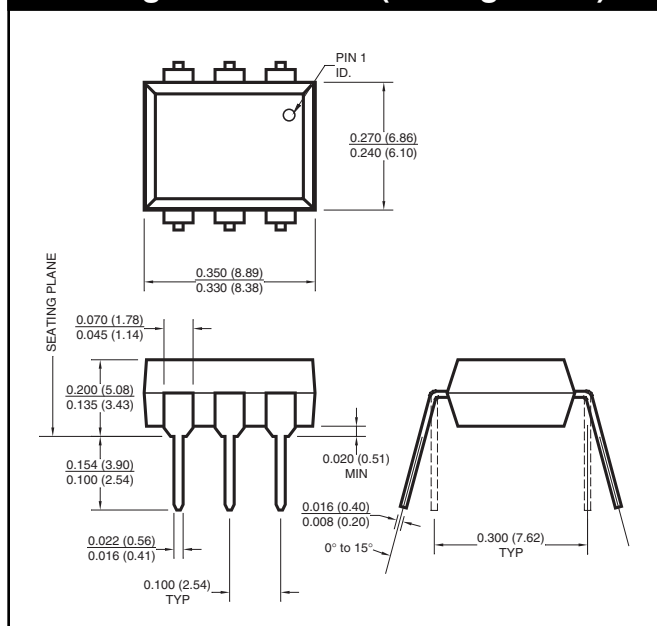


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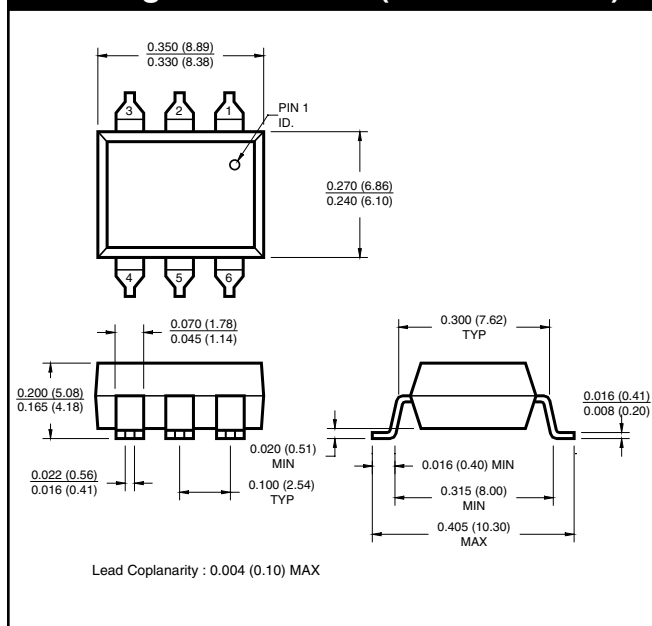
MOC8112

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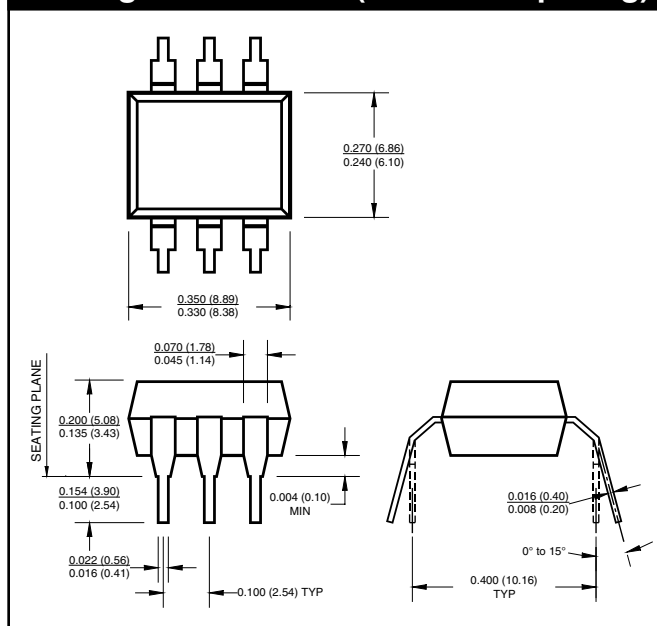
Package Dimensions (Through Hole)



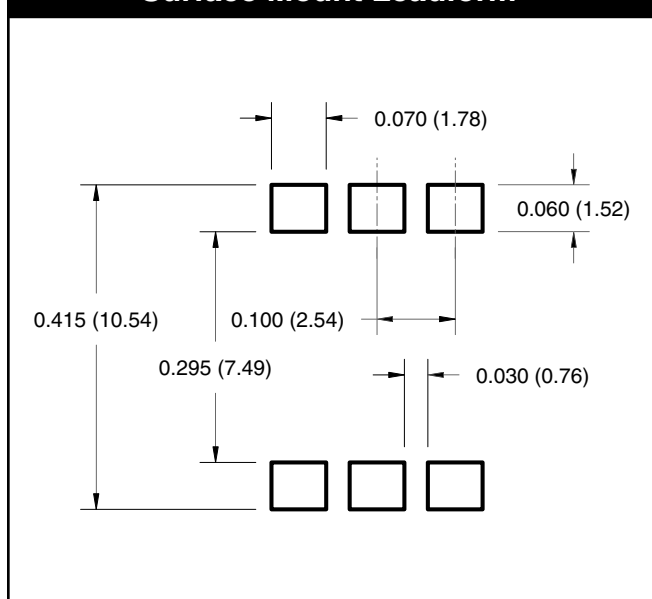
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



**Recommended Pad Layout for
Surface Mount Leadform**



NOTE

All dimensions are in inches (millimeters)

MOC8111

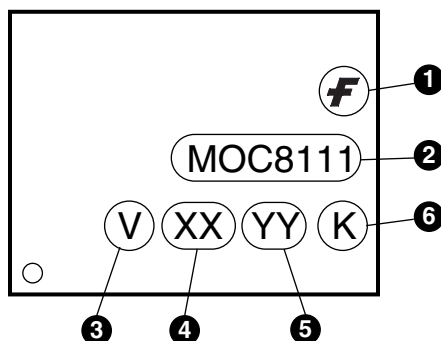
MOC8112

MOC8113

ORDERING INFORMATION¹

Option	Example Part Number	Description
No Suffix	MOC8111	Through Hole
S	MOC8111S	Surface Mount Lead Bend
SD	MOC8111SD	Surface Mount; Tape and Reel
W	MOC8111W	0.4" Lead Spacing
300	MOC8111300	VDE 0884
300W	MOC8111300W	VDE 0884, 0.4" Lead Spacing
3S	MOC81113S	VDE 0884, Surface Mount
3SD	MOC81113SD	VDE 0884, Surface Mount, Tape and Reel

MARKING INFORMATION



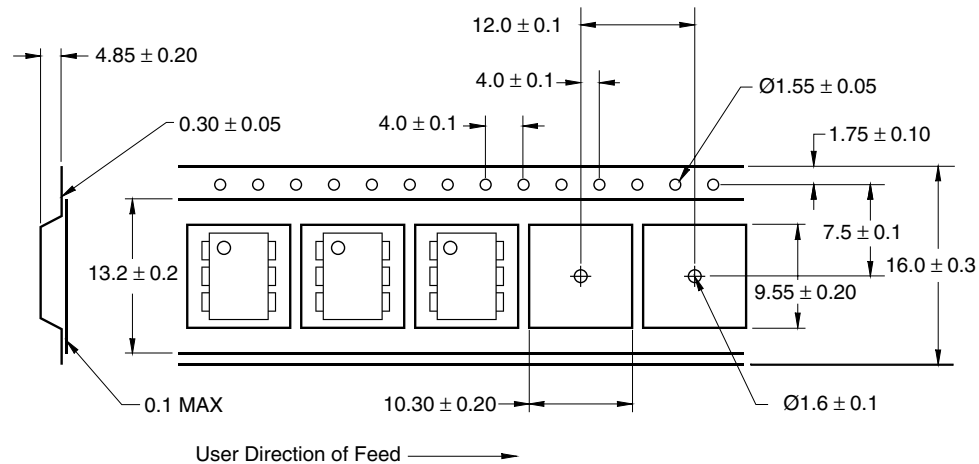
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	Two digit year code, e.g., '03'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

MOC8111

MOC8112

MOC8113

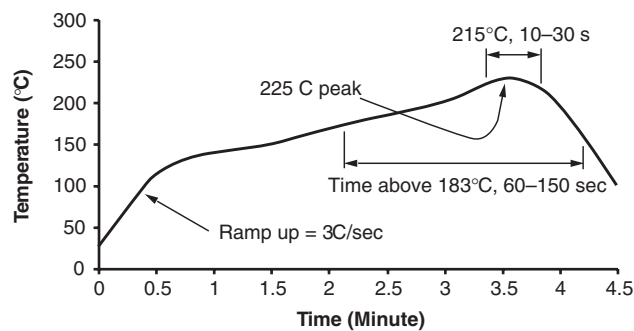
Carrier Tape Specifications



NOTE

All dimensions are in inches (millimeters)

Reflow Profile (Black Package, No Suffix)



- Peak reflow temperature: 225°C (package surface temperature)
- Time of temperature higher than 183°C for 60-150 seconds
- One time soldering reflow is recommended

MOC8111

MOC8112

MOC8113

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.